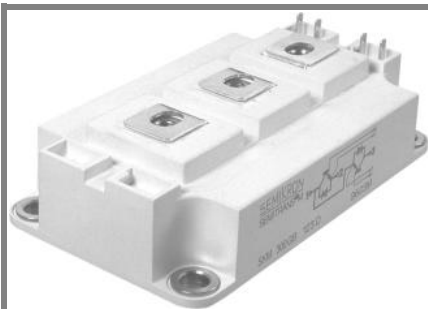


SKM 150GB12T4G



SEMITRANS® 3

IGBT4 Modules

SKM 150GB12T4G

Target Data

Features

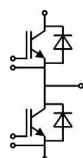
- IGBT4 = 4. Generation (Trench) IGBT
- V_{CEsat} with positive temperature coefficient
- High short circuit capability, self limiting to $6 \times I_{CNOM}$
- Soft switching 4. Generation CAL diode (CAL4)

Typical Applications

- AC inverter drives
- UPS
- Electronic welders at f_{sw} up to 20 kHz

Remarks

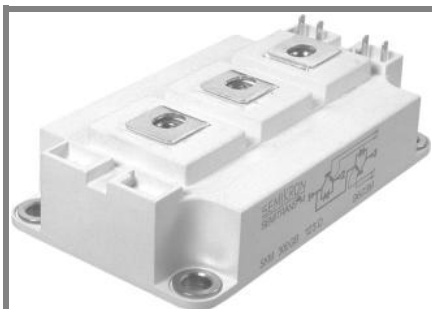
- Case temperature limited to $T_c = 125^\circ\text{C}$ max, recomm. $T_{op} = -40 \dots +150^\circ\text{C}$, product rel. results valid for $T_j \leq 150^\circ$



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Absolute Maximum Ratings			$T_c = 25\text{ }^{\circ}\text{C}$, unless otherwise specified	
Symbol	Conditions		Values	Units
IGBT				
V_{CES}	$T_j = 25\text{ }^{\circ}\text{C}$		1200	V
I_C	$T_j = 175\text{ }^{\circ}\text{C}$	$T_{case} = 25\text{ }^{\circ}\text{C}$	220	A
		$T_{case} = 80\text{ }^{\circ}\text{C}$	170	A
I_{CRM}	$I_{CRM} = 3 \times I_{CNOM}$		450	A
V_{GES}			± 20	V
t_{psc}	$V_{CC} = 600\text{ V}; V_{GE} \leq 15\text{ V}; T_j = 150\text{ }^{\circ}\text{C}$ $V_{CES} < 1200\text{ V}$		10	μs
Inverse Diode				
I_F	$T_j = 175\text{ }^{\circ}\text{C}$	$T_{case} = 25\text{ }^{\circ}\text{C}$	180	A
		$T_{case} = 80\text{ }^{\circ}\text{C}$	135	A
I_{FRM}	$I_{FRM} = 3 \times I_{FNOM}$		450	A
I_{FSM}	$t_p = 10\text{ ms}; \sin.$	$T_j = 175\text{ }^{\circ}\text{C}$	860	A
Module				
$I_{t(RMS)}$			500	A
T_{vj}			-40 ... +175	$^{\circ}\text{C}$
T_{stg}			-40 ... +125	$^{\circ}\text{C}$
V_{isol}	AC, 1 min.		4000	V

Characteristics			T _c = 25 °C, unless otherwise specified			
Symbol	Conditions		min.	typ.	max.	Units
IGBT						
V _{GE(th)}	V _{GE} = V _{CE} , I _C = 6 mA		5	5,8	6,5	V
I _{CES}	V _{GE} = 0 V, V _{CE} = V _{CES} T _J = 25 °C					mA
V _{CE0}				0,8	0,9	V
				0,7	0,8	V
r _{CE}	V _{GE} = 15 V T _J = 25°C T _J = 150°C					mΩ
						mΩ
V _{CE(sat)}	I _{Cnom} = 150 A, V _{GE} = 15 V T _J = 25°C _{chiplev.} T _J = 150°C _{chiplev.}					V
						V
C _{ies}	V _{CE} = 25, V _{GE} = 0 V f = 1 MHz					9,3
C _{oes}						0,58
C _{res}						0,51
Q _G	V _{GE} = -8V /+15V					nC
R _{Gint}	T _J = 25 °C		5			Ω
t _{d(on)}	R _{Gon} = Ω	V _{CC} = 600V I _{Cnom} = 150A T _J = 150 °C V _{GE} = ±15V	14,8			ns
t _r						ns
E _{on}	mJ					
t _{d(off)}	R _{Goff} = Ω					ns
t _f						ns
E _{off}						mJ
R _{th(j-c)}	per IGBT					0,2



SEMITRANS® 3

IGBT4 Modules

SKM 150GB12T4G

Target Data

Features

- IGBT4 = 4. Generation (Trench) IGBT
- V_{CEsat} with positive temperature coefficient
- High short circuit capability, self limiting to $6 \times I_{CNOM}$
- Soft switching 4. Generation CAL diode (CAL4)

Typical Applications

- AC inverter drives
- UPS
- Electronic welders at f_{sw} up to 20 kHz

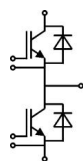
Remarks

- Case temperature limited to $T_c = 125^\circ\text{C}$ max, recomm. $T_{op} = -40 \dots +150^\circ\text{C}$, product rel. results valid for $T_j \leq 150^\circ$

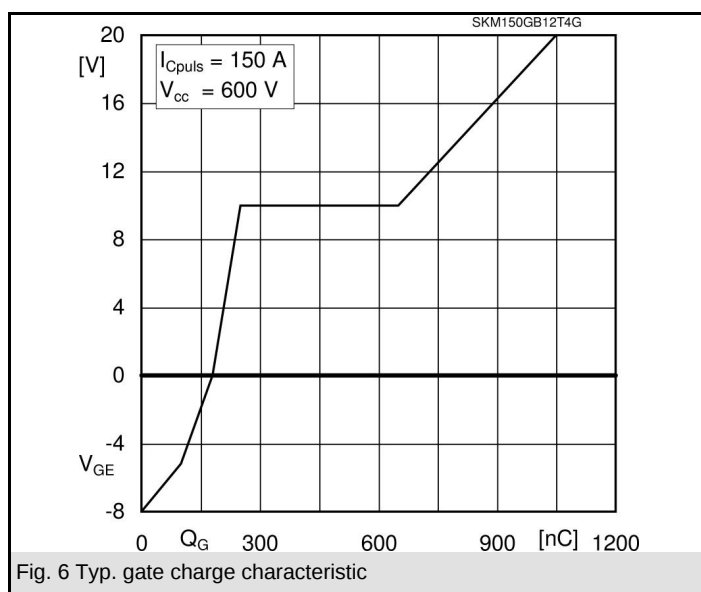
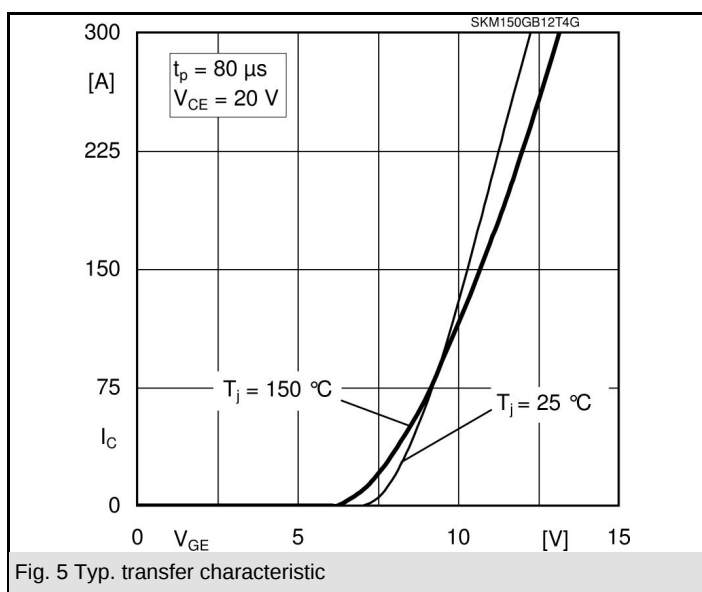
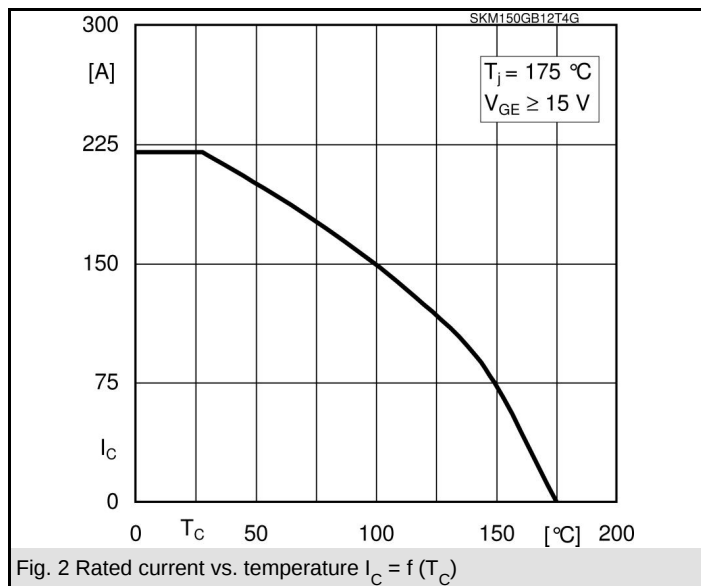
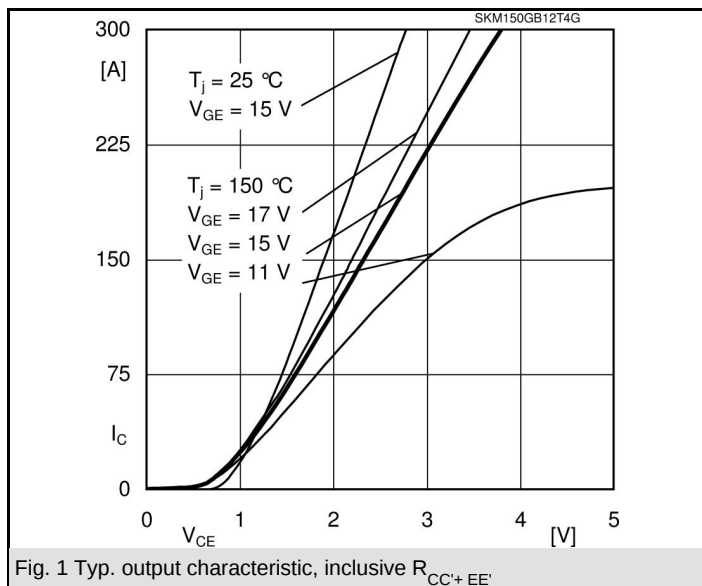
Characteristics						
Symbol	Conditions	min.	typ.	max.	Units	
Inverse Diode						
V _F = V _{EC}	I _{Fnom} = 150 A; V _{GE} = 0 V	T _j = 25 °C _{chiplev.}	2,2	2,5	V	
		T _j = 150 °C _{chiplev.}	2,1	2,45	V	
V _{F0}		T _j = 25 °C	1,3	1,5	V	
		T _j = 150 °C	0,9	1,1	V	
r _F		T _j = 25 °C	6	6,67	mΩ	
		T _j = 150 °C	8	9	mΩ	
I _{RRM} Q _{rr} E _{rr}	I _{Fnom} = 150 A V _{GE} = -15V	T _j = 150 °C	11,3			A μC mJ
R _{th(j-c)}	per diode			0,32		K/W
Freewheeling Diode						
V _F = V _{EC}	I _{Fnom} = A; V _{GE} = V	T _j = °C _{chiplev.}				V
V _{F0}		T _j = °C				V
r _F		T _j = °C				V
I _{RRM} Q _{rr} E _{rr}	I _{Fnom} = A	T _j = °C				A μC mJ
	per diode			K/W		
Module						
L _{CE}			15	20	nH	
R _{CC'+EE'}	res., terminal-chip	T _{case} = 25 °C T _{case} = 125 °C	0,35 0,5			mΩ mΩ
R _{th(c-s)}	per module		0,02	0,038	K/W	
M _s	to heat sink M6		3	5	Nm	
M _t	to terminals M6		2,5	5	Nm	
w			325			g

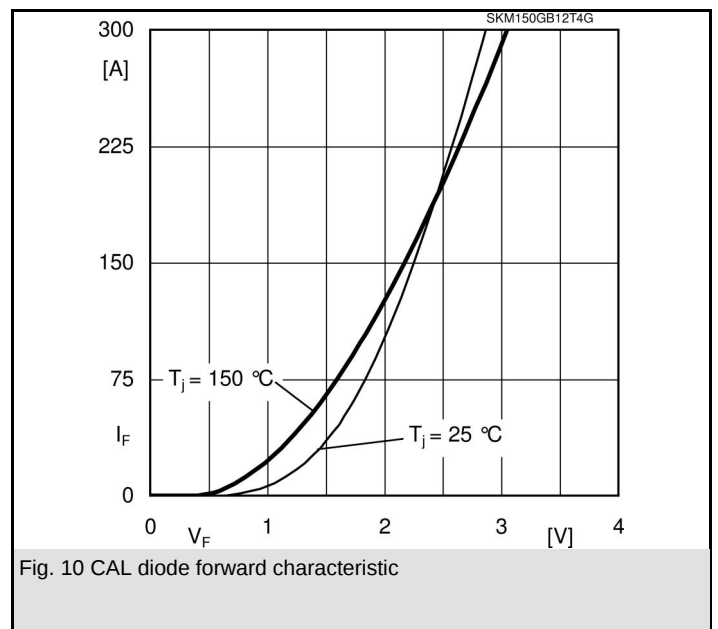
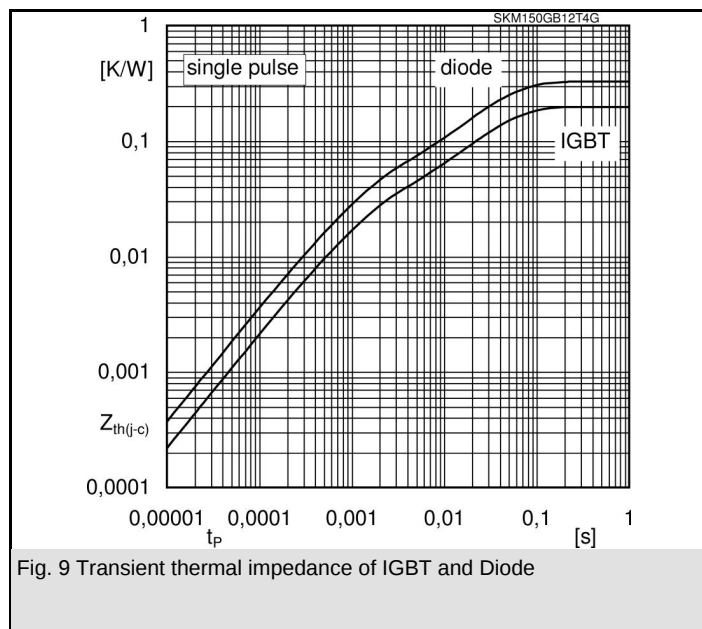
This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.



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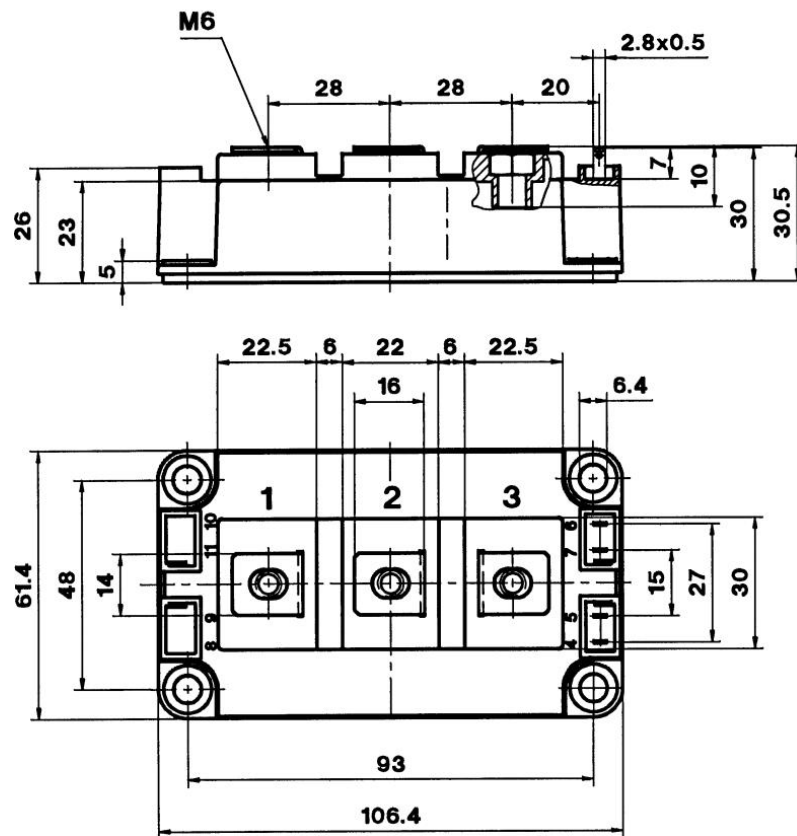


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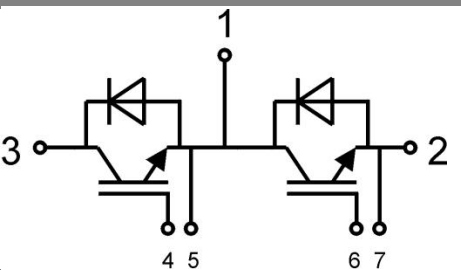
UL recognized file

CASED56

no. E 63 532



Case D56



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Case D56